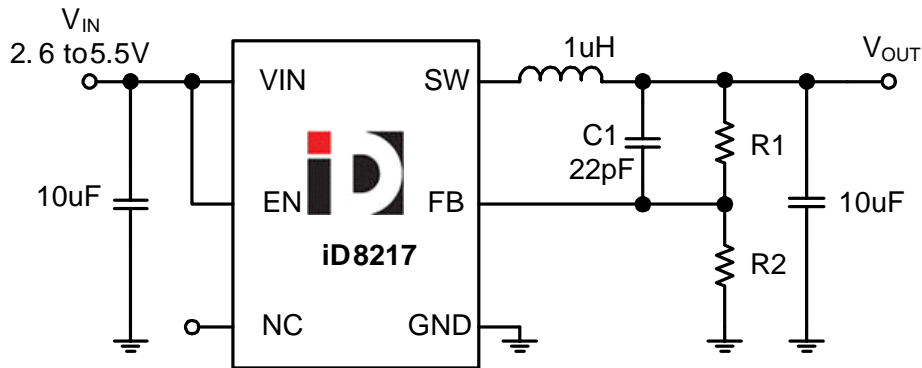


**Typical Application Circuit
(Adjustable Operation)**



Absolute Maximum Ratings

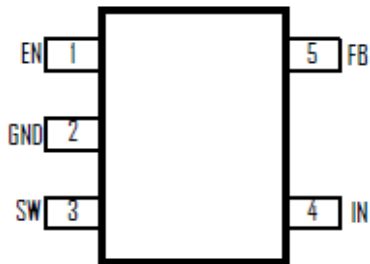
IN, SW, FB, EN Voltage	-0.3V to 6V
Power Dissipation, P_D @ $T_A=25^\circ\text{C}$	
SOT-23-5	600mW
Thermal Resistance, θ_{ja}	
SOT-23-5	167°C/W
Lead Temperature	260°C
Storage Temperature	-65°C to 150°C
ESD Susceptibility	
HBM (Human Body Mode)	2kV
MM (Machine Mode)	200V

Recommended Operating Conditions

Input Voltage V_{IN}	2.6V to 5.5V
EN Input Voltage	0V to V_{IN}
Junction Temperature	-40°C to 125°C
Ambient Operating Temperature	-40°C to 85°C

Pin Configurations

(Top View)

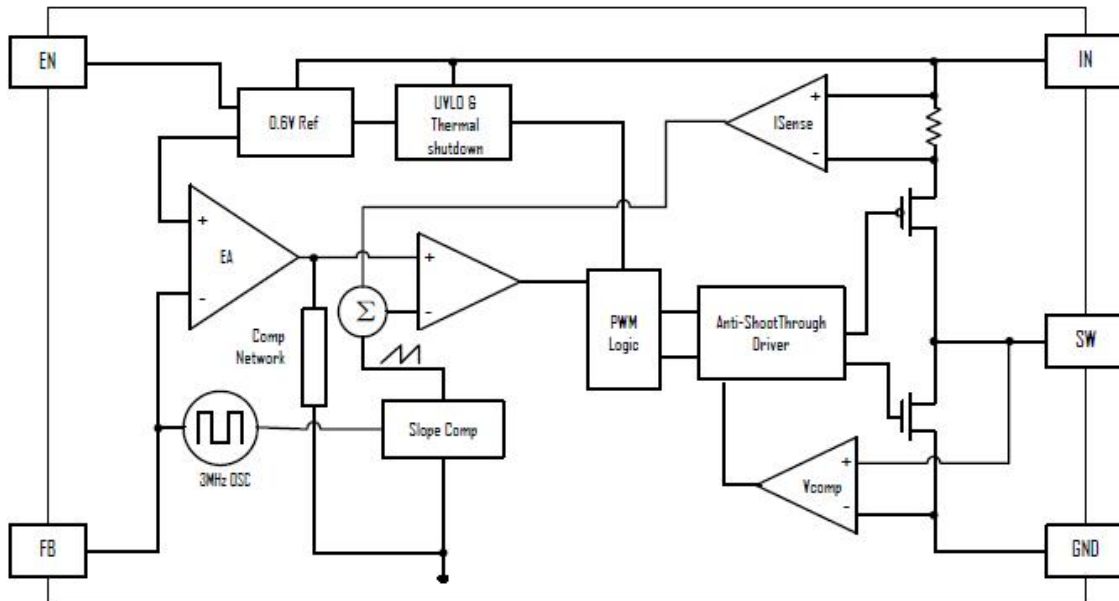


SOT-23-5

Pin Description

SOT-23-5	Name	Description
1	EN	Enable pin for the IC. Drive this pin to high to enable the part, low to disable.
2	GND	Ground.
3	SW	Inductor Connection. Connect an inductor Between SW and the regulator output.
4	VIN	Supply Voltage. Short to PIN. Bypass with a 10 μ F ceramic capacitor to GND
5	FB	Feedback Input. Connect an external resistor divider from the output to FB and GND to set the output to a voltage between 0.6V and VIN

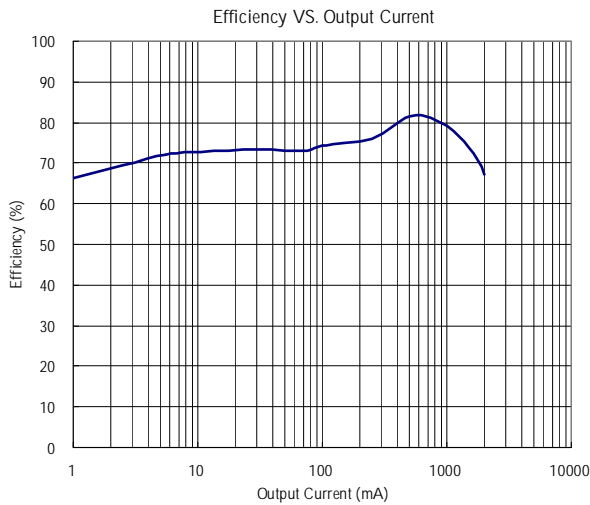
Function Block Diagram



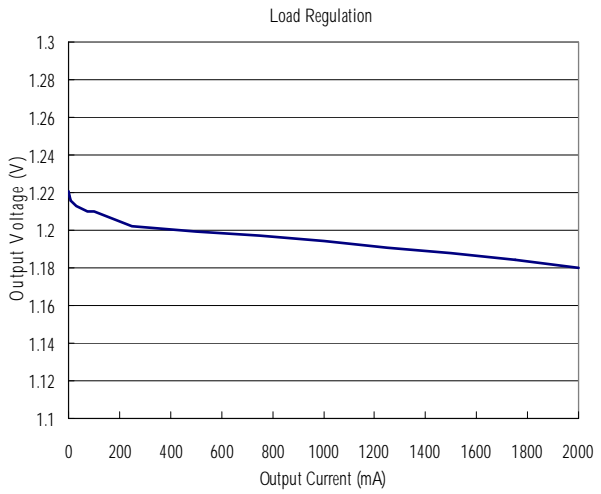
Electrical Characteristics

Parameters	Condition	Min	Typ	Max	Units
Input Voltage Range		2.6		5.5	V
Input UVLO	Rising, Hysteresis=200mV		2.1		V
Input Supply Current	VFB =0.65V		30		μA
Input Shutdown Current			0.1	1	μA
FB Feedback Voltage	V _{IN} =2.5 to 5V	0.588	0.6	0.612	V
FB Input Current			0.01		μA
Output Voltage Range		0.6		V _{IN}	V
Load Regulation			0.15		%A
Line Regulation	V _{IN} =2.6 to 5.5V		0.04		%/V
Switching Frequency		2.4	3	3.6	MHz
NMOS Switch On Resistance	I _{SW} =200mA		100		mΩ
PMOS Switch On Resistance	I _{SW} =200mA		80		mΩ
PMOS Switch Current Limit			2.5		A
SW Leakage Current	V _{IN} =5.5V, V _{SW} =0 or 5.5V, EN=GND			10	μA
EN Input Current	EN=GND			1	μA
EN Input Low Voltage				0.4	V
EN Input High Voltage		1.5			V
Thermal Shutdown	Rising, Hysteresis =15°C		160		°C

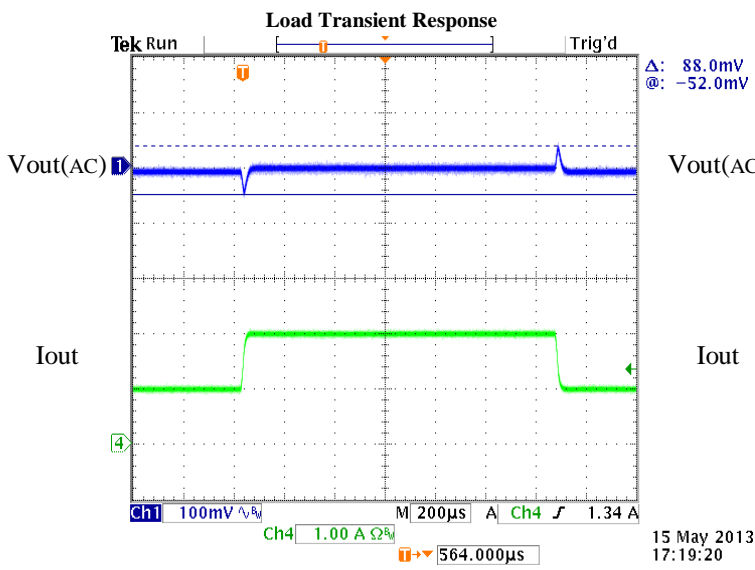
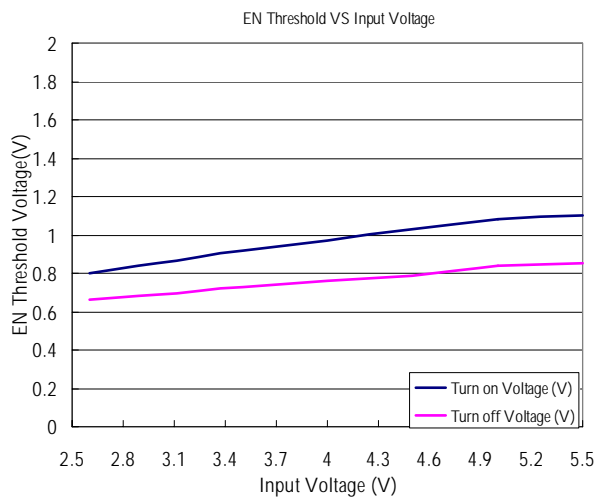
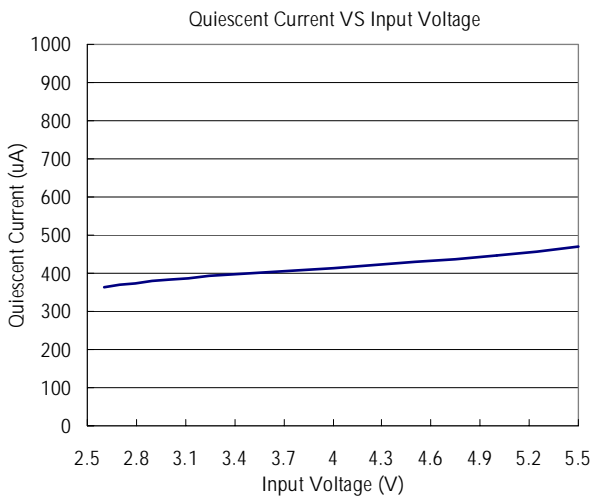
Typical Operating Characteristics



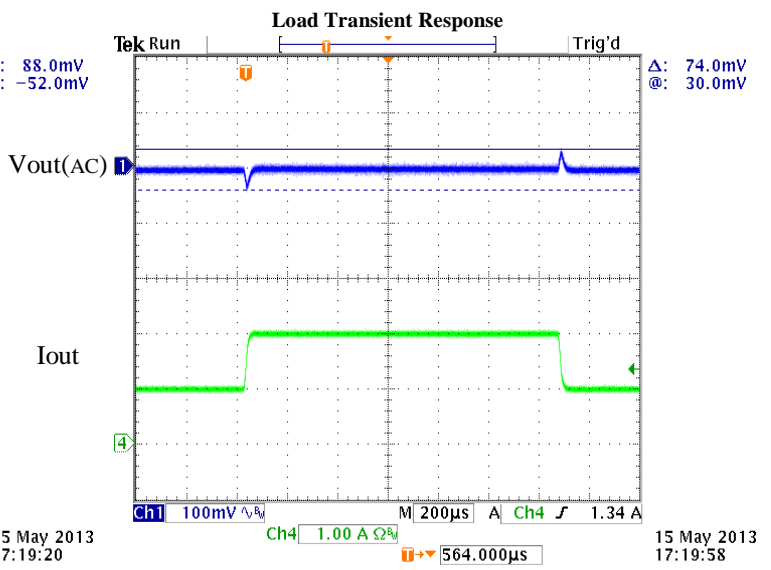
Condition: Vin=5V, Vout=1.2V



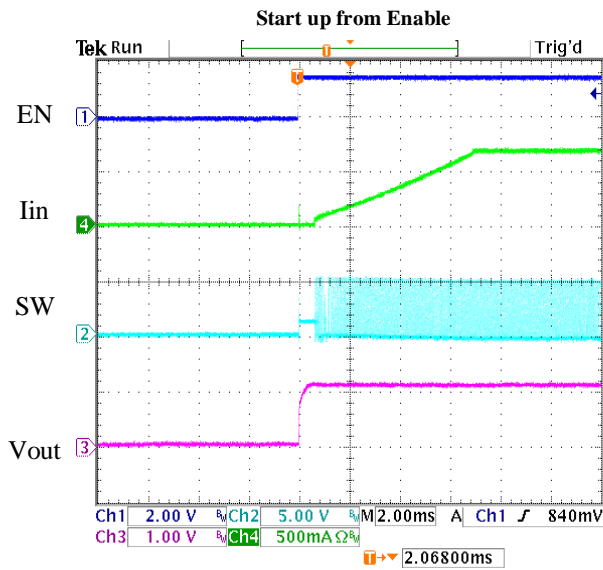
Condition: Vin=5V, Vout=1.2V



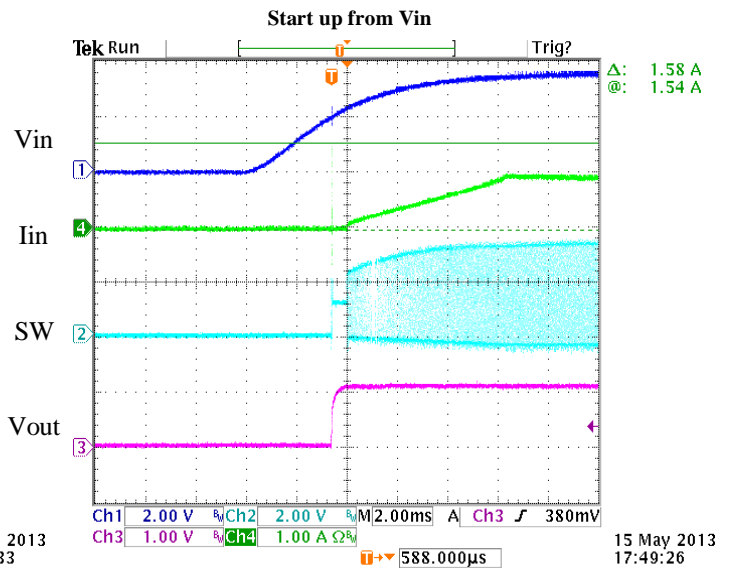
Condition: Vin=3.6V, Vout=1.2V, Iout=1A to 2A



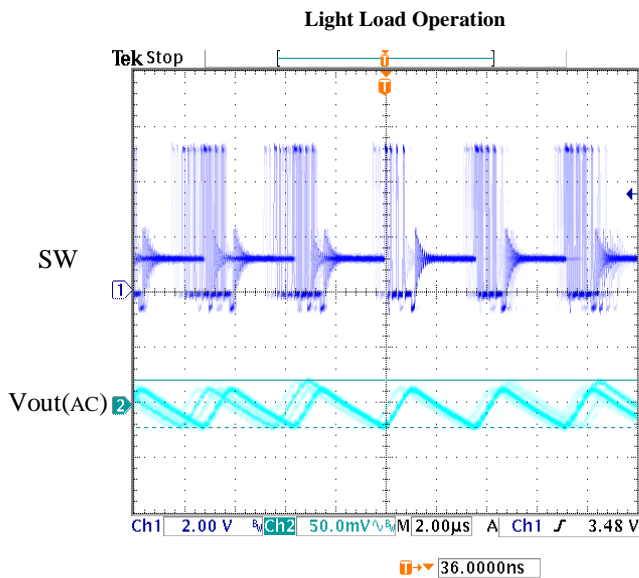
Condition: Vin=5V, Vout=1.2V, Iout=1A to 2A



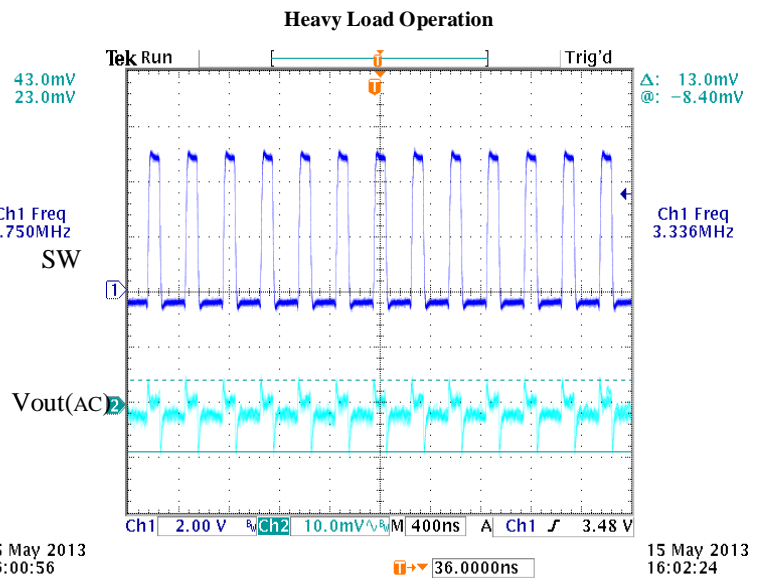
Condition: Vin=5V, VEN=1.5V, Vout=1.2V, Iout=2A



Condition: Vin=VEN=5V, Vout=1.2V, Iout= 2A



Condition: Vin=5V, Vout=1.2V, Iout=100mA



Condition: Vin=5V, Vout=1.2V, Iout=2A

Applications Information

FUNCTION DESCRIPTION

The iD8217 high efficiency switching regulator is a small, simple, DC-to-DC step-down converter capable of delivering up to 2A of output current. The device operates in pulse-width modulation (PWM) at 3MHz from a 2.6V to 5.5V input voltage and provides an output voltage from 0.6V to V_{IN} , making the iD8217 ideal for on-board post-regulation applications. An internal synchronous rectifier improves efficiency and eliminates the typical Schottky free-wheeling diode. Using the on resistance of the internal high-side MOSFET to sense switching currents eliminates current-sense resistors, further improving efficiency and cost

Loop Operation

iD8217 uses a PWM current-mode control scheme. An open-loop comparator compares the integrated voltage-feedback signal against the sum of the amplified current-sense signal and the slope compensation ramp. At each rising edge of the internal clock, the internal high-side MOSFET turns on until the PWM comparator terminates the on cycle. During this on-time, current ramps up through the inductor, sourcing current to the output and storing energy in the inductor. The current mode feedback system regulates the peak inductor current as a function of the output voltage error signal. During the off cycle, the internal high-side P-channel MOSFET turns off, and the internal low-side N-channel MOSFET turns on. The inductor releases the stored energy as its current ramps down while still providing current to the output.

Current Sense

An internal current-sense amplifier senses the current through the high-side MOSFET during on time and produces a proportional current signal, which is used to sum with the slope compensation signal. The summed signal then is compared with the error

amplifier output by the PWM comparator to terminate the on cycle.

Current Limit

There is a cycle-by-cycle current limit on the high-side MOSFET. When the current flowing out of SW exceeds this limit, the high-side MOSFET turns off and the synchronous rectifier turns on. iD8217 utilizes a frequency fold-back mode to prevent overheating during short-circuit output conditions. The device enters frequency fold-back mode when the FB voltage drops below 200mV, limiting the current to I_{PEAK} and reducing power dissipation. Normal operation resumes upon removal of the short-circuit condition.

Soft-start

iD8217 has an internal soft-start circuitry to reduce supply inrush current during startup conditions. When the device exits under-voltage lockout (UVLO), shutdown mode, or restarts following a thermal-overload event, the I soft-start circuitry slowly ramps up current available at SW.

UVLO and Thermal Shutdown

If V_{IN} drops below 1.9V, the UVLO circuit inhibits switching. Once V_{IN} rises above 2.1V, the UVLO clears, and the soft-start sequence activates. Thermal-overload protection limits total power dissipation in the device. When the junction temperature exceeds $T_J = +160^{\circ}\text{C}$, a thermal sensor forces the device into shutdown, allowing the die to cool. The thermal sensor turns the device on again after the junction temperature cools by 15°C , resulting in a pulsed output during continuous overload conditions. Following a thermal-shutdown condition, the soft-start sequence begins.

DESIGN PROCEDURE

Setting Output Voltages

Output voltages are set by external resistors. The FB threshold is 0.6V.

$$R_{TOP} = R_{BOTTOM} \times [(V_{OUT} / 0.6) - 1]$$

Inductor Selection

The peak-to-peak ripple is limited to 30% of the maximum output current. This places the peak current far enough from the minimum over current trip level to ensure reliable operation while providing enough current ripples for the current mode converter to operate stably. In this case, for 2A maximum output current, the maximum inductor ripple current is 667 mA.

The inductor size is estimated as following equation:

$$L_{IDEAL} = (V_{IN(MAX)} - V_{OUT}) / I_{RIPPLE} * D_{MIN} * (1 / F_{OSC})$$

Therefore, for $V_{OUT} = 1.8V$,

The inductor values is calculated to be $L = 0.60\mu H$.

Chose $1\mu H$

For $V_{OUT} = 1.2V$,

The inductor values is calculated to be $L = 0.469\mu H$.

Chose $0.47\mu H$

The resulting ripple is

$$I_{RIPPLE} = (V_{IN(MAX)} - V_{OUT}) / L_{ACTUAL} * D_{MIN} * (1 / F_{OSC})$$

When,

$$V_{OUT} = 1.8V, I_{RIPPLE} = 403mA$$

$$V_{OUT} = 1.2V, I_{RIPPLE} = 665mA$$

Output Capacitor Selection

For most applications a nominal $10\mu F$ or $22\mu F$ capacitor is suitable. The iD8217 internal compensation is designed for a fixed corner frequency that is equal to

$$FC = \frac{1}{2\pi \sqrt{C_{OUT} * L}}$$

For example, for $V_{OUT} = 1.8V$, $L = 1\mu H$, $C_{OUT} = 10\mu F$, for $V_{OUT} = 1.2V$, $L = 0.47\mu H$, $C_{OUT} = 22\mu F$

The output capacitor keeps output ripple small and

ensures control-loop stability. The output capacitor must also have low impedance at the switching frequency. Ceramic, polymer, and tantalum capacitors are suitable, with ceramic exhibiting the lowest ESR and high-frequency impedance. Output ripple with a ceramic output capacitor is approximately as follows:

$$V_{RIPPLE} = I_{L(PEAK)} [1 / (2\pi \times f_{OSC} \times C_{OUT})]$$

If the capacitor has significant ESR, the output ripple component due to capacitor ESR is as follows:

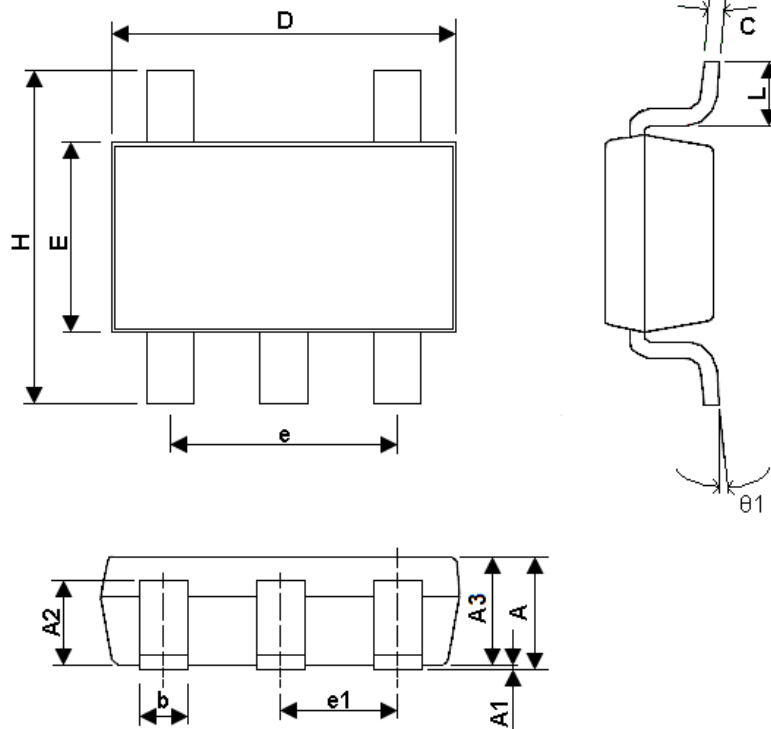
$$V_{RIPPLE(ESR)} = I_{L(PEAK)} \times ESR$$

Input Capacitor Selection

The input capacitor in a DC-to-DC converter reduces current peaks drawn from the battery or other input power source and reduces switching noise in the controller. The impedance of the input capacitor at the switching frequency should be less than that of the input source so high-frequency switching currents do not pass through the input source. The output capacitor keeps output ripple small and ensures control-loop stability.

Packaging

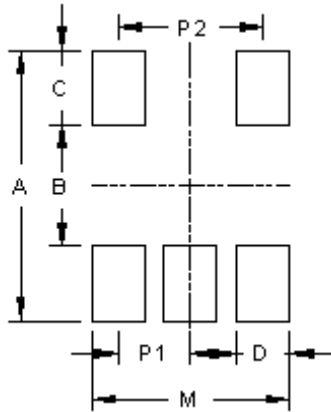
SOT-23-5



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCH		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.00	1.10	1.30	0.039	0.043	0.051
A1	0.00	---	0.10	0.000	---	0.004
A2	0.70	0.80	0.90	0.027	0.031	0.035
b	0.35	0.40	0.50	0.013	0.016	0.020
C	0.10	0.15	0.25	0.004	0.006	0.001
D	2.70	2.90	3.10	0.106	0.114	0.122
E	1.50	1.60	1.80	0.059	0.063	0.071
e	---	1.90(TYP)	---	---	0.075	---
H	2.60	2.80	3.00	0.102	0.110	0.118
L	0.370	---	---	0.015	---	---
$\theta 1$	1°	5°	9°	1°	5°	9°
e1	---	0.95(TYP)	---	---	0.037	---

Footprints

SOT-23-5



Package	Number of PIN	Footprint Dimension (mm)							Tolerance
		P1	P2	A	B	C	D	M	
SOT-23-5	5	0.95	1.90	3.60	1.60	1.00	0.70	2.60	±0.10